

FS7KM-16A

HIGH-SPEED SWITCHING USE

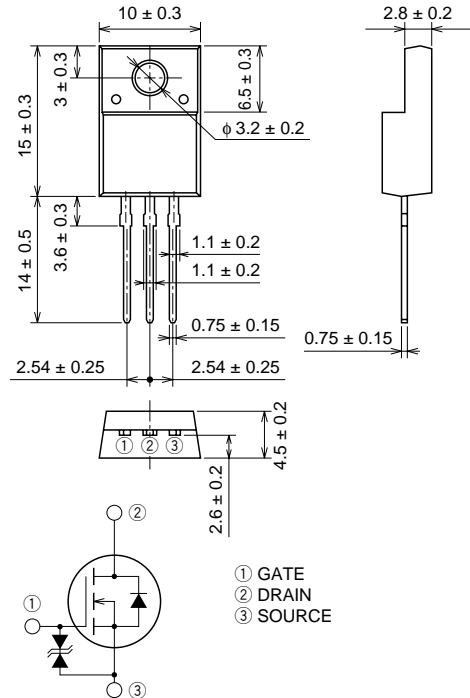
FS7KM-16A



- V_{DSS} 800V
- $r_{DS(ON)}$ (MAX) 1.64Ω
- I_D 7A
- V_{iso} 2000V

OUTLINE DRAWING

Dimensions in mm



TO-220FN

APPLICATION

SMPS, DC-DC Converter, battery charger, power supply of printer, copier, HDD, FDD, TV, VCR, personal computer etc.

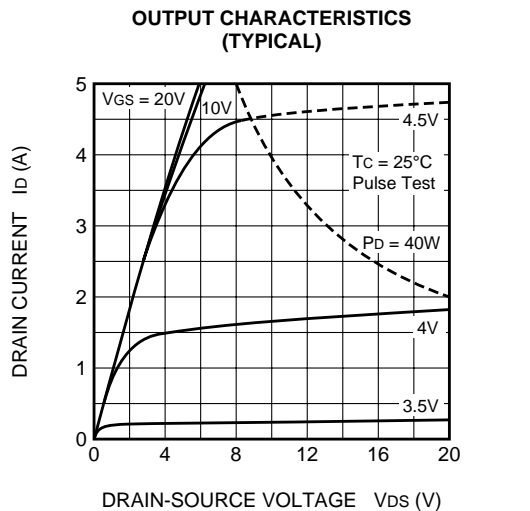
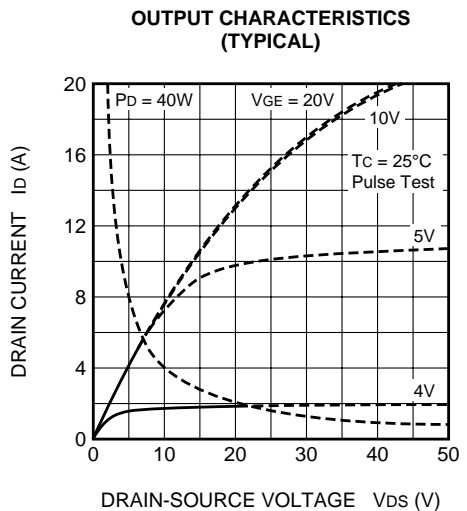
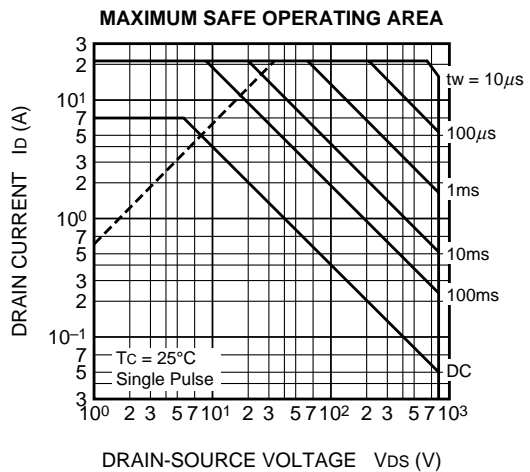
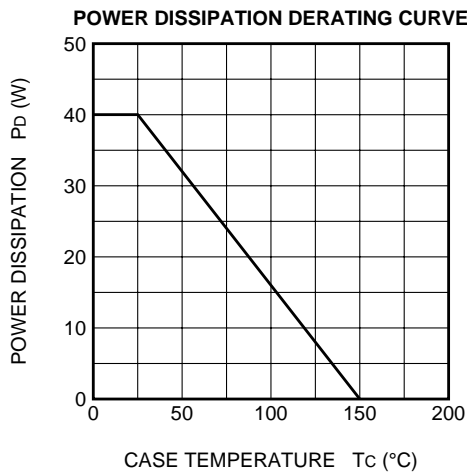
MAXIMUM RATINGS (T_c = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{DSS}	Drain-source voltage	$V_{GS} = 0V$	800	V
V_{GSS}	Gate-source voltage	$V_{DS} = 0V$	± 30	V
I_D	Drain current		7	A
I_{DM}	Drain current (Pulsed)		21	A
P_D	Maximum power dissipation		40	W
T_{ch}	Channel temperature		-55 ~ +150	°C
T_{stg}	Storage temperature		-55 ~ +150	°C
V_{iso}	Isolation voltage	AC for 1 minute, Terminal to case	2000	V _{rms}
—	Weight	Typical value	2	g

ELECTRICAL CHARACTERISTICS (Tch = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	Id = 1mA, VGS = 0V	800	—	—	V
V (BR) GSS	Gate-source breakdown voltage	IGS = ±100μA, VDS = 0V	±30	—	—	V
IGSS	Gate-source leakage current	VGS = ±25V, VDS = 0V	—	—	±10	μA
IDSS	Drain-source leakage current	VDS = 800V, VGS = 0V	—	—	1	mA
VGS (th)	Gate-source threshold voltage	Id = 1mA, VDS = 10V	2	3	4	V
rDS (ON)	Drain-source on-state resistance	Id = 3A, VGS = 10V	—	1.26	1.64	Ω
VDS (ON)	Drain-source on-state voltage	Id = 3A, VGS = 10V	—	3.78	4.92	V
yfs	Forward transfer admittance	Id = 3A, VDS = 10V	4.2	7.0	—	S
Ciss	Input capacitance	VDS = 25V, VGS = 0V, f = 1MHz	—	1380	—	pF
Coss	Output capacitance		—	140	—	pF
Crss	Reverse transfer capacitance		—	28	—	pF
td (on)	Turn-on delay time	VDD = 200V, Id = 3A, VGS = 10V, RGEN = RGS = 50Ω	—	25	—	ns
tr	Rise time		—	28	—	ns
td (off)	Turn-off delay time		—	185	—	ns
tf	Fall time		—	46	—	ns
VSD	Source-drain voltage	IS = 3A, VGS = 0V	—	1.0	1.5	V
Rth (ch-c)	Thermal resistance	Channel to case	—	—	3.13	°C/W

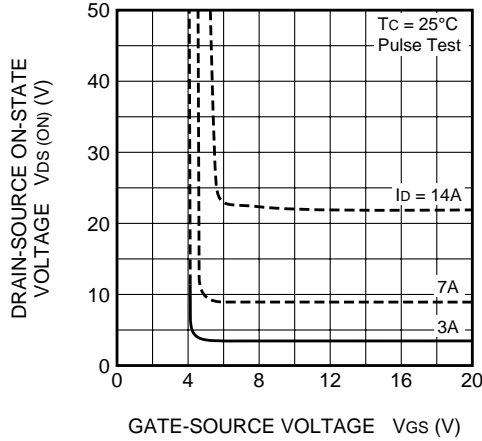
PERFORMANCE CURVES



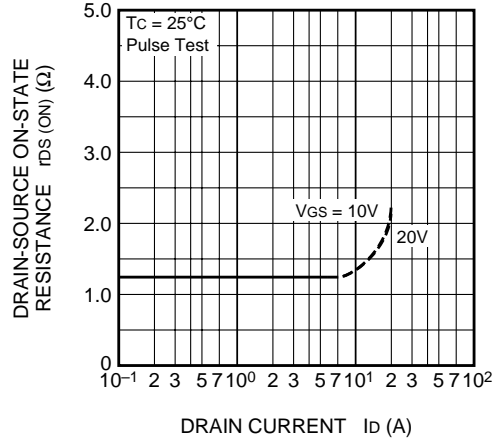
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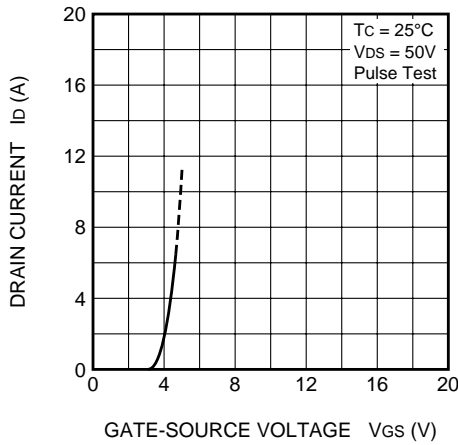
ON-STATE VOLTAGE VS. GATE-SOURCE VOLTAGE (TYPICAL)



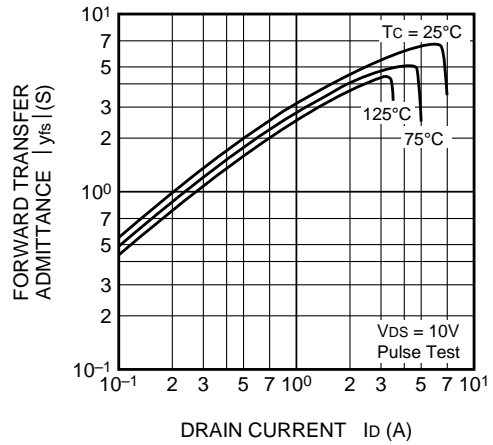
ON-STATE RESISTANCE VS. DRAIN CURRENT (TYPICAL)



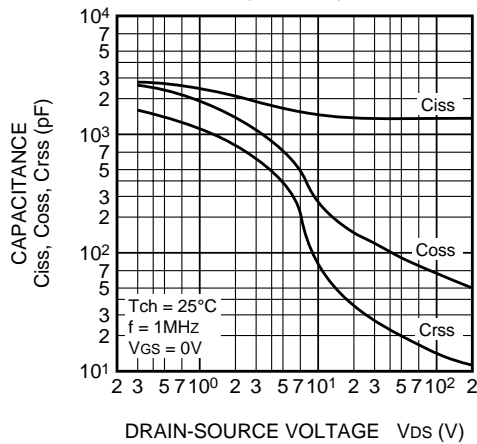
TRANSFER CHARACTERISTICS (TYPICAL)



FORWARD TRANSFER ADMITTANCE VS. DRAIN CURRENT (TYPICAL)



CAPACITANCE VS. DRAIN-SOURCE VOLTAGE (TYPICAL)



SWITCHING CHARACTERISTICS (TYPICAL)

